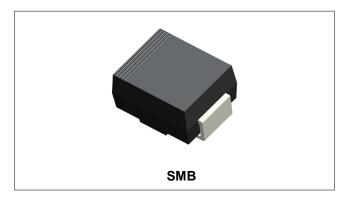






SK310B SCHOTTKY RECTIFIER



Features

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term
- reliability
- Green products in compliance the ROHS directive
- Terminals finish: Tin Lead-free plated
- This is a Pb Free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings(limiting values, T_C =25°C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	100	V
Average Rectified Forward Current	I _F (AV)	50% duty cycle @T _L =115°C, rectangular wave form	3	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	110	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 3A, Pulse, T _J = 25 °C	0.77	0.85	V
	V _{F2}	@ 3A, Pulse, T _J = 125 °C	0.63	0.80	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_{R_1} T_J = 25 ^{\circ}\text{C}$	0.0001	0.6	mA
	I _{R2}	$@V_R = \text{rated } V_{R_s} T_J = 125 ^{\circ}\text{C}$	0.04	20.0	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$	92	250	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nΗ
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%







Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Repetitive peek reverse current	I _{RRM}	Tp=2us F=1KHZsquare	1	Α
Typical Thermal Resistance Junction to Lead	$R_{ heta JL}$	DC operation	17	°C/W
Typical Thermal Resistance Junction to Case	R₀JA	DC operation	75	°C/W
Approximate Weight	wt	-	0.09	g

Ratings and Characteristics Curves

Figure 1 Typical Forward Characteristics

10°

10°

25°C

10°

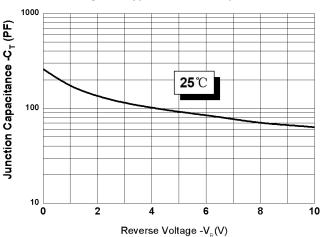
25°C

Forward Voltage -V_F(V)

Figure 2 Typical Reverse Characteristics

10°
10°
10°
10°
25°C
10°
25°C
10°
Reverse Voltage -V_R(V)

Figure 3 Typical Junction Capacitance



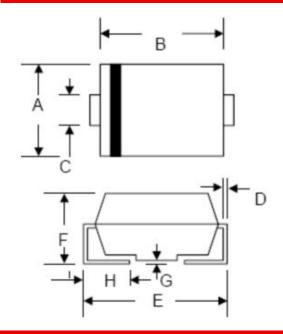
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Mechanical Dimensions SMB



OVANDOL	Millimeters		Inches		
SYMBOL	Min.	Max.	Min.	Max.	
А	3.30	3.94	0.130	0.155	
В	4.06	4.70	0.160	0.185	
С	1.80	2.20	0.071	0.087	
D	0.152	0.305	0.006	0.012	
Е	4.80	5.59	0.189	0.220	
F	2.10	2.60	0.083	0.102	
G	0.051	0.203	0.002	0.008	
Н	0.76	1.52	0.030	0.060	

Ordering Information

Device	Package	Shipping
SK310B	SMB (Pb-Free)	3000pcs / reel
SK310BTR	SMB (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

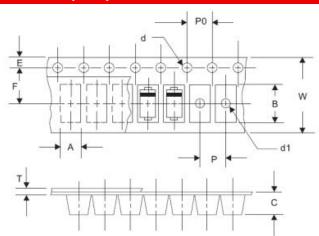
Marking Diagram

Where XXXXX is YYWWL

B310 XXXXX B = Package type
3 = Forward Current (3A)
10 = Reverse Voltage (100V)
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification SMB



SYMBOL	Millimeters		
	Min.	Max.	
Α	3.70	3.90	
В	5.70	5.90	
С	2.32	2.52	
d	1.40	1.60	
E	1.40	1.60	
F	5.60	5.70	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
T	0.25	0.35	
W	11.80	12.20	

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